

# Automotive Dual N-Channel 40 V (D-S) 175 °C MOSFET

| PRODUCT SUMMARY                                  |        |  |  |  |  |
|--|--------|--|--|--|--|
| V <sub>DS</sub> (V)                              | 40     |  |  |  |  |
| $R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$  | 0.0093 |  |  |  |  |
| $R_{DS(on)}(\Omega)$ at $V_{GS} = 4.5 \text{ V}$ | 0.0111 |  |  |  |  |
| I <sub>D</sub> (A) per leg                       | 30     |  |  |  |  |
| Configuration                                    | Dual   |  |  |  |  |

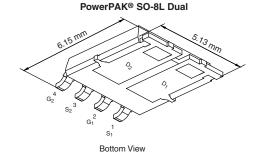
## **FEATURES**

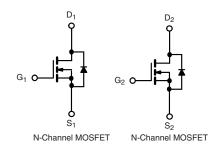
- TrenchFET® Power MOSFET
- 100 % R<sub>g</sub> and UIS Tested
- AEC-Q101 Qualifiedd
- Material categorization:
   For definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>





ROHS COMPLIANT HALOGEN FREE





| ORDERING INFORMATION            |                  |
|---------------------------------|------------------|
| Package                         | PowerPAK SO-8L   |
| Lead (Pb)-free and Halogen-free | SQJ912AEP-T1-GE3 |

| ARAMETER  |                         | SYMBOL                            | LIMIT         | UNIT |
|---|-------------------------|-----------------------------------|---------------|------|
| Drain-Source Voltage  |                         | $V_{DS}$                          | 40            | V    |
| Gate-Source Voltage   |                         | $V_{GS}$                          | ± 20          | V    |
| Continuous Drain Currenta   | T <sub>C</sub> = 25 °C  | 1                                 | 30            |      |
| Continuous Drain Current  | T <sub>C</sub> = 125 °C | T <sub>C</sub> = 125 °C           | 29            |      |
| Continuous Source Current (Diode Conduction) <sup>a</sup>   |                         | I <sub>S</sub>                    | 30            | Α    |
| Pulsed Drain Current <sup>b</sup>   |                         | I <sub>DM</sub>                   | 120           |      |
| Single Pulse Avalanche Current  | L = 0.1 mH              | I <sub>AS</sub>                   | 26            |      |
| Single Pulse Avalanche Energy   | L=U.I IIIH              | E <sub>AS</sub>                   | 34            | mJ   |
| Maximum Dawar Dissinationh  | T <sub>C</sub> = 25 °C  | Ъ                                 | 48            | W    |
| Maximum Power Dissipation <sup>b</sup>  | T <sub>C</sub> = 125 °C | $P_{D}$                           | 16            | VV   |
| Operating Junction and Storage Temperature Range Soldering Recommendations (Peak Temperature) <sup>e, f</sup> |                         | T <sub>J</sub> , T <sub>stg</sub> | - 55 to + 175 | 00   |
|   |                         | -                                 | 260           | °C   |

| THERMAL RESISTANCE RATINGS |                        |            |       |      |  |  |
|----------------------------|------------------------|------------|-------|------|--|--|
| PARAMETER                  |                        | SYMBOL     | LIMIT | UNIT |  |  |
| Junction-to-Ambient        | PCB Mount <sup>c</sup> | $R_{thJA}$ | 85    | °C/W |  |  |
| Junction-to-Case (Drain)   |                        | $R_{thJC}$ | 3.1   | C/VV |  |  |

#### Notes

- a. Package limited.
- b. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %.
- c. When mounted on 1" square PCB (FR4 material).
- d. Parametric verification ongoing.

S13-2015-Rev. A, 30-Sep-13

- e. See solder profile (<a href="www.vishay.com/doc?73257">www.vishay.com/doc?73257</a>). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- f. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.



| PARAMETER                                     | SYMBOL                   | TES   | T CONDITIONS                                     | MIN. | TYP.   | MAX.   | UNIT |
|---|--------------------------|---|--|------|--------|--------|------|
| Static  |                          | _   |  |      | •      |        |      |
| Drain-Source Breakdown Voltage                | V <sub>DS</sub>          | V <sub>GS</sub> =   | = 0 V, I <sub>D</sub> = 250 μA                   | 40   | -      | -      | V    |
| Gate-Source Threshold Voltage                 | V <sub>GS(th)</sub>      | V <sub>DS</sub> =   | = V <sub>GS</sub> , I <sub>D</sub> = 250 μA      | 1.5  | 2      | 2.5    | V    |
| Gate-Source Leakage                           | I <sub>GSS</sub>         | V <sub>DS</sub> =   | $0 \text{ V}, \text{ V}_{GS} = \pm 20 \text{ V}$ | -    | -      | ± 100  | nA   |
|   |                          | $V_{GS} = 0 V$  | V <sub>DS</sub> = 40 V                           | -    | -      | 1      |      |
| Zero Gate Voltage Drain Current               | I <sub>DSS</sub>         | V <sub>GS</sub> = 0 V   | V <sub>DS</sub> = 40 V, T <sub>J</sub> = 125 °C  | -    | -      | 50     | μΑ   |
|   |                          | $V_{GS} = 0 V$  | V <sub>DS</sub> = 40 V, T <sub>J</sub> = 175 °C  | -    | -      | 150    |      |
| On-State Drain Current <sup>a</sup>           | I <sub>D(on)</sub>       | V <sub>GS</sub> = 10 V  | $V_{DS} \ge 5 V$                                 | 30   | -      | -      | Α    |
|   |                          | V <sub>GS</sub> = 10 V  | I <sub>D</sub> = 9.7 A                           | -    | 0.0077 | 0.0093 |      |
| Drain-Source On-State Resistance <sup>a</sup> |                          | V <sub>GS</sub> = 4.5 V   | I <sub>D</sub> = 8.9 A                           | -    | 0.0093 | 0.0111 |      |
| Drain-Source On-State Resistance              | R <sub>DS(on)</sub>      | V <sub>GS</sub> = 10 V  | I <sub>D</sub> = 9.7 A, T <sub>J</sub> = 125 °C  | -    | -      | 0.0138 | Ω    |
|   |                          | V <sub>GS</sub> = 10 V  | I <sub>D</sub> = 9.7 A, T <sub>J</sub> = 175 °C  | -    | -      | 0.0169 |      |
| Forward Transconductance <sup>b</sup>         | 9 <sub>fs</sub>          | $V_{DS}$  | = 15 V, I <sub>D</sub> = 10 A                    | -    | 58     | -      | S    |
| Dynamic <sup>b</sup>                          |                          |   |  |      |        |        |      |
| Input Capacitance                             | C <sub>iss</sub>         |   |  | -    | 1438   | 1835   |      |
| Output Capacitance                            | C <sub>oss</sub>         | $V_{GS} = 0 V$  | $V_{DS} = 20 \text{ V}, f = 1 \text{ MHz}$       | =.   | 217    | 271    | рF   |
| Reverse Transfer Capacitance                  | C <sub>rss</sub>         | 7   |  | -    | 91     | 114    |      |
| Total Gate Charge <sup>c</sup>                | Qg                       |   |  | -    | 25.6   | 38     |      |
| Gate-Source Charge <sup>c</sup>               | Q <sub>gs</sub>          | V <sub>GS</sub> = 10 V  | $V_{DS} = 20 \text{ V}, I_{D} = 11.3 \text{ A}$  | =.   | 4      | -      | nC   |
| Gate-Drain Charge <sup>c</sup>                | Q <sub>gd</sub>          | 7   |  | -    | 4      | -      |      |
| Gate Resistance                               | R <sub>g</sub>           |   | f = 1 MHz  | 0.72 | 1.44   | 2.2    | Ω    |
| Turn-On Delay Time <sup>c</sup>               | t <sub>d(on)</sub>       |   |  | =.   | 10     | 15     |      |
| Rise Time <sup>c</sup>                        | t <sub>r</sub>           | $V_{DD}$ = 20 V, $R_L$ = 20 $\Omega$<br>$I_D \cong$ 1 A, $V_{GEN}$ = 10 V, $R_g$ = 1 $\Omega$ |  | -    | 9      | 14     |      |
| Turn-Off Delay Time <sup>c</sup>              | t <sub>d(off)</sub>      |   |  | -    | 23     | 35     | ns   |
| Fall Time <sup>c</sup>                        | t <sub>f</sub>           |   |  | -    | 11     | 17     |      |
| Source-Drain Diode Ratings and Char-          | acteristics <sup>b</sup> |   |  |      |        |        |      |
| Pulsed Current <sup>a</sup>                   | I <sub>SM</sub>          |   |  | =.   |        | 120    | Α    |
| Forward Voltage                               | $V_{SD}$                 | I <sub>F</sub> =  | _  | 0.8  | 1.1    | V      |      |

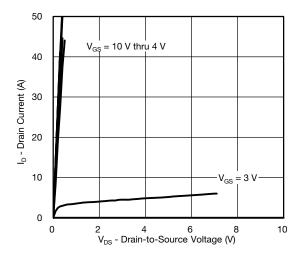
## **Notes**

- a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

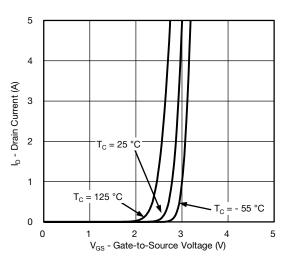
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



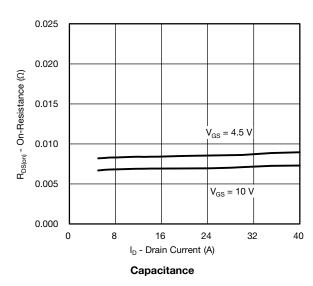
# **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)

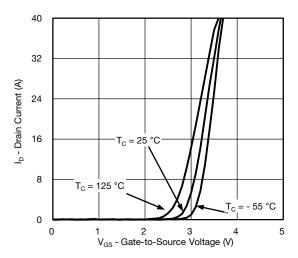


## **Output Characteristics**

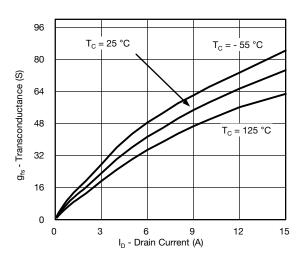


## **Transfer Characteristics**

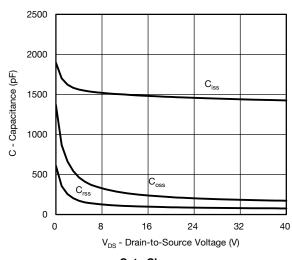




## **Transfer Characteristics**

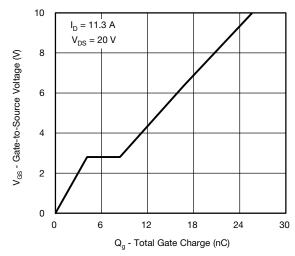


## Transconductance

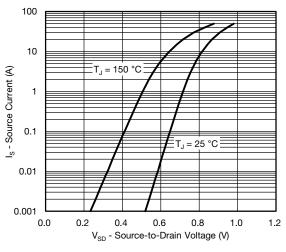




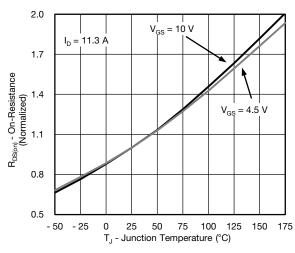
# **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



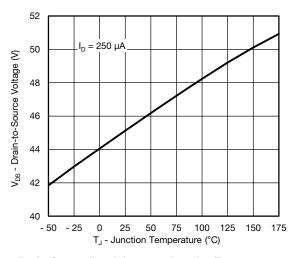
## **Gate Charge**



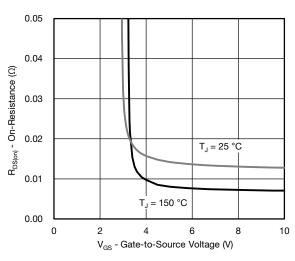
## **Source Drain Diode Forward Voltage**



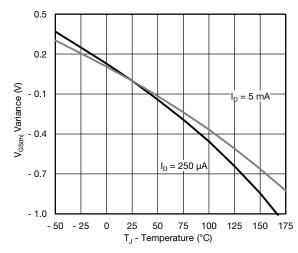
On-Resistance vs. Junction Temperature



## **Drain-Source Breakdown vs. Junction Temperature**



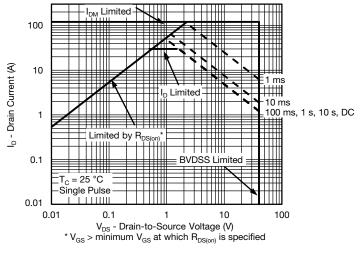
## On-Resistance vs. Gate-to-Source Voltage



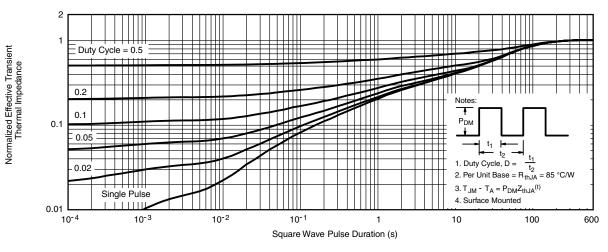
**Threshold Voltage** 



# **THERMAL RATINGS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



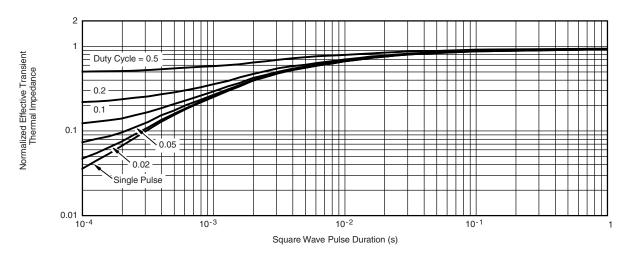
**Safe Operating Area** 



Normalized Thermal Transient Impedance, Junction-to-Ambient



# **THERMAL RATINGS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



## Normalized Thermal Transient Impedance, Junction-to-Case

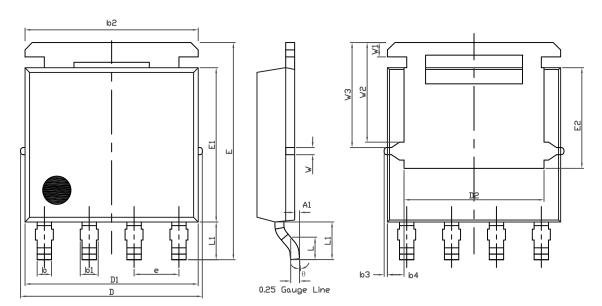
#### Note

- The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
  - Normalized Transient Thermal Impedance Junction-to-Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

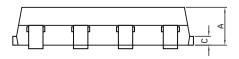
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="https://www.vishay.com/ppg?62876">www.vishay.com/ppg?62876</a>.

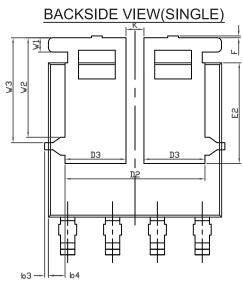


# PowerPAK® SO-8L Case Outline 2



**TOPSIDE VIEW** 





BACKSIDE VIEW(DUAL)

| DIM  |      | MILLIMETERS |           |       | INCHES    |       |  |
|------|------|-------------|-----------|-------|-----------|-------|--|
| DIM. | MIN. | NOM.        | MAX.      | MIN.  | NOM.      | MAX.  |  |
| Α    | 1.00 | 1.07        | 1.14      | 0.039 | 0.042     | 0.045 |  |
| A1   | 0.00 | -           | 0.127     | 0.00  | -         | 0.005 |  |
| b    | 0.33 | 0.41        | 0.48      | 0.013 | 0.016     | 0.019 |  |
| b1   | 0.44 | 0.51        | 0.58      | 0.017 | 0.020     | 0.023 |  |
| b2   | 4.80 | 4.90        | 5.00      | 0.189 | 0.193     | 0.197 |  |
| b3   |      | 0.094       | •         |       | 0.004     |       |  |
| b4   |      | 0.47        |           |       | 0.019     |       |  |
| С    | 0.20 | 0.25        | 0.30      | 0.008 | 0.010     | 0.012 |  |
| D    | 5.00 | 5.13        | 5.25      | 0.197 | 0.202     | 0.207 |  |
| D1   | 4.80 | 4.90        | 5.00      | 0.189 | 0.193     | 0.197 |  |
| D2   | 3.86 | 3.96        | 4.06      | 0.152 | 0.156     | 0.160 |  |
| D3   | 1.63 | 1.73        | 1.83      | 0.064 | 0.068     | 0.072 |  |
| е    |      | 1.27 BSC    |           |       | 0.050 BSC |       |  |
| Е    | 6.05 | 6.15        | 6.25      | 0.238 | 0.242     | 0.246 |  |
| E1   | 4.27 | 4.37        | 4.47      | 0.168 | 0.172     | 0.176 |  |
| E2   | 2.75 | 2.85        | 2.95      | 0.108 | 0.112     | 0.116 |  |
| F    | -    | -           | 0.15      | -     | -         | 0.006 |  |
| L    | 0.62 | 0.72        | 0.82      | 0.024 | 0.028     | 0.032 |  |
| L1   | 0.92 | 1.07        | 1.22      | 0.036 | 0.042     | 0.048 |  |
| K    |      | 0.51        |           |       | 0.020     |       |  |
| W    |      | 0.23        | .23 0.009 |       |           |       |  |
| W1   |      | 0.41        |           | 0.016 |           |       |  |
| W2   |      | 2.82        |           |       | 0.111     |       |  |
| W3   |      | 2.96        |           | 0.117 |           |       |  |
| q    | 0°   | -           | 10°       | 0°    | -         | 10°   |  |

ECN: S19-0643-Rev. B, 05-Aug-2019

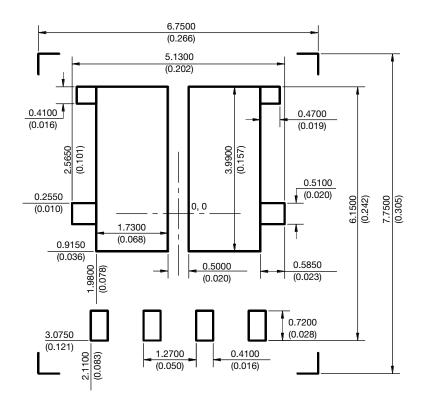
DWG: 6044

## Note

• Millimeters will gover



## RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L DUAL



Recommended Minimum Pads Dimensions in mm (inches) Keep-out 6.75 (0.266) x 7.75 (0.305)



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# PowerPAK® SO-8, PowerPAK® SO-8L, PowerPAK® 1212-8, PowerPAK® 1212-8S, PowerPAK® 1212-8W, PowerPAIR® 6 x 3.7, PowerPAIR® 6 x 5, PowerPAIR® 3 x 3



7401 = example base part number or marking code <sup>a</sup>

# = Siliconix logo

LL = lot code

 $\triangle$  = ESD symbol

= pin 1 indicator

T = assembly factory code

Y = year ode

W = week code

F = wafer fab code

#### Note

a. These digits will be a code, if indicated on the datasheet. Otherwise, the digits will be the base number like indicated in the example

| YEAR CODE | YEAR CODE |      |      |  |  |  |  |  |
|-----------|-----------|------|------|--|--|--|--|--|
| YEAR      | CODE      | YEAR | CODE |  |  |  |  |  |
| 2010      | 0         | 2020 | 0    |  |  |  |  |  |
| 2011      | 1         | 2021 | 1    |  |  |  |  |  |
| 2012      | 2         | 2022 | 2    |  |  |  |  |  |
| 2013      | 3         | 2023 | 3    |  |  |  |  |  |
| 2014      | 4         | 2024 | 4    |  |  |  |  |  |
| 2015      | 5         | 2025 | 5    |  |  |  |  |  |
| 2016      | 6         | 2026 | 6    |  |  |  |  |  |
| 2017      | 7         | 2027 | 7    |  |  |  |  |  |
| 2018      | 8         | 2028 | 8    |  |  |  |  |  |
| 2019      | 9         | 2029 | 9    |  |  |  |  |  |





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| WEEK CODE |      |
|-----------|------|
| WORK WEEK | CODE |
| 1 to 6    | 1    |
| 7 to 12   | 2    |
| 13 to 18  | 3    |
| 19 to 24  | 4    |
| 25 to 30  | 5    |
| 31 to 36  | 6    |
| 37 to 42  | 7    |
| 43 to 48  | 8    |
| 49 to 53  | 9    |

The current marking strategy is reflected. Contact your local sales representative for historical marking strategies for these packages.

# **SQ MOSFET Ordering Information**

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# **Ordering Code for SQ Series Automotive MOSFET**

Standard ordering code for SQ series of automotive MOSFETs can be derived per the following table:

| PACKAGE TYPE                 | DATASHEET PART NUMBER    | ORDERING SUFFIX | ORDERING PART NUMBER              |
|------------------------------|--------------------------|-----------------|-----------------------------------|
| PowerPAK® SC-70              | Datasheet part number    | -T1 GE3         | Datasheet part number + "-T1_GE3" |
| FOWEIFAR® 30-70              | (example: SQA401EJ)      | -11_GL3         | (example: SQA401EJ-T1_GE3)        |
| PowerPAK® 1212               | Datasheet part number    | -T1_GE3         | Datasheet part number + "-T1_GE3" |
| FOWEIFAR* 1212               | (example: SQ7415AENW)    | -11_GE3         | (example: SQ7415AENW-T1_GE3)      |
| PowerPAK® SO-8L              | Datasheet part number    | -T1 GE3         | Datasheet part number + "-T1_GE3" |
| FOWEIFAR® 30-6L              | (example: SQJ459EP)      | -11_GE3         | (example: SQJ459EP-T1_GE3)        |
| PowerPAK® 8 x 8L             | Datasheet part number    | -T1 GE3         | Datasheet part number + "-T1_GE3" |
| POWEIPAN® 6 X 6L             | (example: SQJQ402E)      | -11_GE3         | (example: SQJQ402E-T1_GE3)        |
| SC-70                        | Datasheet part number    | T1 OF0          | Datasheet part number + "-T1_GE3" |
| 50-70                        | (example: SQ1431EH)      | -T1_GE3         | (example: SQ1431EH-T1_GE3)        |
| COT 00                       | Datasheet part number    | T1 OF0          | Datasheet part number + "-T1_GE3" |
| SOT-23                       | (example: SQ2389ES)      | -T1_GE3         | (example: SQ2389ES-T1_GE3)        |
| TSOP-6                       | Datasheet part number    | -T1 GE3         | Datasheet part number + "-T1_GE3" |
| 1507-0                       | (example: SQ3427EV)      | -11_GE3         | (example: SQ3427EV-T1_GE3)        |
| 00.0                         | Datasheet part number    | T1 OF0          | Datasheet part number + "-T1_GE3" |
| SO-8                         | (example: SQ4005EY)      | -T1_GE3         | (example: SQ4005EY-T1_GE3)        |
| TO-252 / DPAK,               | Datasheet part number    | CE2             | Datasheet part number + "_GE3"    |
| Reverse lead DPAK            | (example: SQD10N30-330H) | _GE3            | (example: SQD10N30-330H_GE3)      |
| TO-263 / D <sup>2</sup> PAK, | Datasheet part number    | CE2             | Datasheet part number + "_GE3"    |
| D <sup>2</sup> PAK-7L        | (example: SQM40022EM)    | _GE3            | (example: SQM40022EM_GE3)         |
| TO 200 TO 200                | Datasheet part number    | CE2             | Datasheet part number + "_GE3"    |
| TO-220, TO-262               | (example: SQV120N10-3M8) | _GE3            | (example: SQV120N10-3M8_GE3)      |

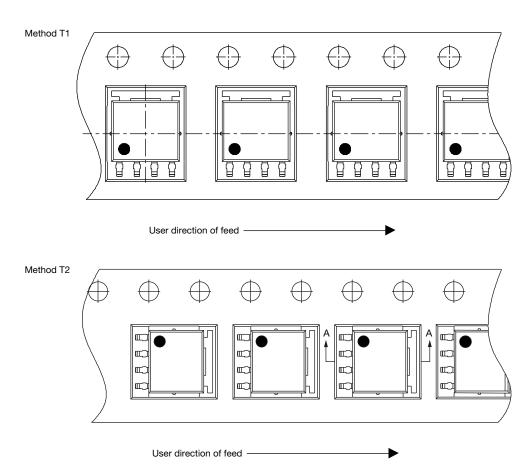
## Note

For bare die parts and for non-standard orientations in tape (such as T2, T4) please contact your local sales or marketing for ordering code information



# **Device Orientation for PowerPAK® SO-8L**

| DEVICE ORIENTATION                    |        |  |  |  |
|---------------------------------------|--------|--|--|--|
| PACKAGE                               | METHOD |  |  |  |
| PowerPAK SO-8L/BWL auto/BWL 2mil auto | T1/T2  |  |  |  |



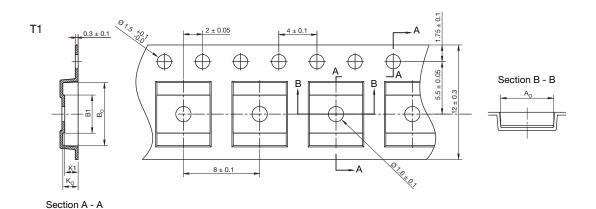
Revision control of this drawing is maintained through Document Control, Pack Specification-PACK-0007-24

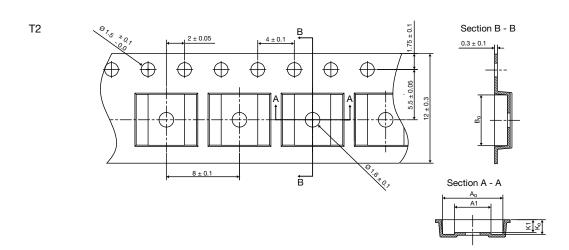
## Note

• For carrier tape drawing 93-5259-X, use version -1



# PowerPAK® SO-8L Carrier Tape





| Version               | A <sub>O</sub> | A1   | B <sub>O</sub> | B1       | K <sub>O</sub> | K1        | Quantity per reel |
|-----------------------|----------------|--|----------------|----------|----------------|-----------|-------------------|
| T1 / - 1              | 5.55 ± 0.1     | -  | 6.60 ± 0.1     | 4 ± 0.15 | 1.6 ± 0.1      | 1.4 ± 0.1 | 3000              |
| T2 / - 2 <sup>a</sup> | 6.60 ± 0.1     | $6.60 \pm 0.1$ $4 \pm 0.15$ $5.55 \pm 0.1$ |                | -        | 1.6 ± 0.1      | 1.4 ± 0.1 | 3000              |

#### Notes

- a. Not standard offering. Please contact local sales office for availability.
- $^{(1)}$  10 sprocket hole pitch cumulative tolerance  $\pm$  0.2 mm.
- (2) Camber not to exceed 1 mm in 100 mm, also not to exceed 1.5 cm in 1 m actually.
- (3) Material: black conductive or black static dissipative.
- $^{(4)}$  A<sub>o</sub> and B<sub>o</sub> measured on a plane 0.3 mm above the bottom of the pocket.
- (5) K<sub>o</sub> measured from a plane on the inside bottom of the pocket to the top surface of carrier.
- (6) It should be measured from:
  - a. sprocket hole to pocket center.
  - b. sprocket hole to pocket hole.
- (7) All size in mm unless specified.
- (8) Tolerance will be  $\pm$  0.1 mm unless specified.
- (9) Vishay part number must be labeled at all reels of carrier tape.
- (10) Surface resistivity:  $10^4$  to  $10^{11}$   $\Omega$ .
- (11) Version suffix as above table shown.

ECN: C15-1433-Rev. F, 02-Nov-15

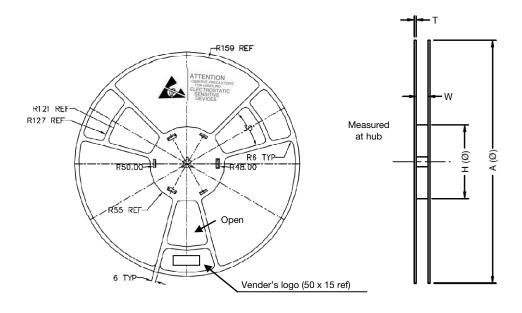
DWG: 93-5259-X

Revision: 02-Nov-15 1 Document Number: 69632



# Reel

# 330 mm Reel (Lock Reel)



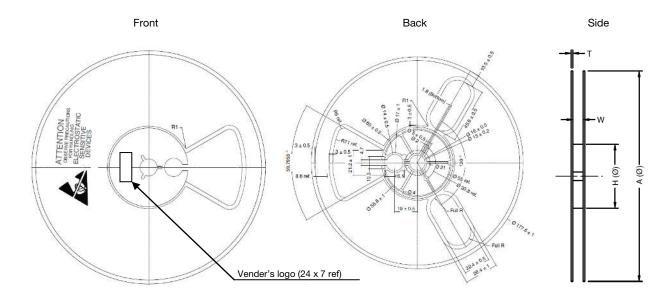
#### Notes

- 1. Material: antistatic or conductor plastic
- 2. All dimensions in mm
- 3. ESD-surface resistivity -10<sup>4</sup>  $\Omega$  to 10<sup>11</sup>  $\Omega$
- 4. Color: black

| VER | APPLICATIO  | DN   | Α       | W                                | TAPE WIDTH | Н       | T             |
|-----|---|--|---------|----------------------------------|------------|---------|---------------|
| - 1 | SOIC-14/16<br>TO-251 (Short Lead)<br>TO-252/TO-252 (Reverse Lead)<br>PLCC-20<br>TSSOP-8/14/16/20/28<br>SSOP-24<br>SOIC-16 (W)<br>PLCC20   | PowerPAK MLF 9 x 9 PowerPAK MLP 6 x 6 MLF 8 x 8 PowerPAK 8 x 8L PowerPAK 8 x 8 MLP57/MLP66/MLP77/MLP46 PowerPAK 5 x 9  | 330 ± 2 | 16.4 <sup>+2</sup><br>-0         | 16         | 100 ± 1 | 2.5 ± 0.5     |
| - 2 | SOIC-8 (N), SOIC-8 (N) epad<br>MSOP-8/10<br>PowerPAK® SO-8<br>PowerPAK 1212<br>PowerPAK 1212-8W<br>MICRO FOOT®<br>MLP33-5, MLP33-8, MLP33-10<br>QFN (4 x 4)/(3 x 3)/DFN-10 (3 x 3)<br>MLP44/MLP4535/MLP55/MLP65/MLP56 | PolarPAK® PowerPAIR® 6 x 5 PowerPAIR 6 x 3 J PowerPAIR SO-8L PolarPAK1215 PowerPAIR 6 x 3.7 PowerPAK SO-8L PowerPAK SO-8L PowerPAK SO-8DCWL Power PAIR 3 x 3 S Power PAIR 3 x 3 F Power PAIR 3 x 3 F | 330 ± 2 | 12.4 +2 -0                       | 12         | 100 ± 1 | 2.5 ± 0.5     |
| - 4 | SOT-23/143<br>SC70<br>MICRO FOOT  | TSOP-6, 1206-8 ChipFET<br>PowerPAK SC70<br>PowerPAK SC75   | 330 ± 2 | 8.4 +1.5<br>-0                   | 8.4        | 100 ± 1 | 2.5 ± 0.5     |
| - 5 | SOIC-20W/24W<br>D2PAK<br>SSOP-28<br>QSOP-36   | PowerPAK MLF 10 x 10<br>MLPA6C<br>PLCC28   | 330 ± 2 | 24.4 +2 -0                       | 24         | 100 ± 1 | 2.5 ± 0.5     |
| - 8 | KGD   |  | 330 ± 2 | 16.4 <sup>+2</sup> <sub>-0</sub> | 16         | 130 ± 1 | $2.5 \pm 0.5$ |

Revision: 01-Feb-2021 1 Document Number: 71385

# 178 mm Reel (Complete Reel)



#### Notes

- 1. Material: antistatic or conductor plastic
- 2. All dimensions in mm
- 3. ESD-surface resistivity -10<sup>4</sup>  $\Omega$  to 10<sup>11</sup>  $\Omega$  4. Color: black

| VER  | APPLICATION  |   | Α       | W                                 | TAPE WIDTH | Н      | T          |
|--|--|---|---------|-----------------------------------|------------|--------|------------|
| - 3  | SOT-23/143<br>TSOP-5/6/SC70JW-8L<br>1206-8 ChipFET®<br>SC70/SC75A/SC89<br>MICRO FOOT<br>SC-89 (SOT-666)<br>SOT23-5, 6<br>KGD<br>WCSP<br>PowerPAK 0806<br>PowerPAK SC70 | PowerPAK SC75 MiniQFN PowerPAK MLP22-5 PowerPAK ChipFET PowerPAK SC75-6L (PIC) PowerPAK TSC75-6L (PIC) TDFN4 1.2 x 1.6, TDFN8 2 x 2 Thin PowerPAK SC-70 Thin PowerPAK SC-75 µDFN-6L 1 x 1 µDFN-4L 1 x 1 | 178 ± 2 | 8.4 <sup>+1.5</sup> <sub>-0</sub> | 8.4        | 62 ± 2 | 1.5 ± 0.5  |
| - 7  | MICRO FOOT<br>PowerPAK 2 x 5   | KGD   | 178 ± 2 | 12.4 +2 -0                        | 12         | 55 ± 2 | 1.6 ± 0.25 |
| ECN: C21-0040-Rev. CA, 01-Feb-2021<br>DWG: 93-5211-X |  |   |         |                                   |            |        |            |



| N-CHANNEL ACCELERATED OPERATING LIFE TEST RESULT |               |  |  |  |  |
|--|---------------|--|--|--|--|
| Sample Size                                      | 15 334        |  |  |  |  |
| Equivalent Device Hours                          | 6 915 815 331 |  |  |  |  |
| Failure Rate in FIT                              | 0.132         |  |  |  |  |

Failure Rate in FIT is calculated according to JEDEC Standard JESD85, *Methods for Calculating Failure Rates in Units of FITs*, based on accelerated high temperature operating life test results by using an apparent activation energy of 0.7 eV. The junction temperature of the device at use is assumed to be 55 °C. A constant failure rate distribution is assumed. The upper confidence bound of the failure rate is 60 %.



# **Silicon Technology Reliability**

Vishay Siliconix

| 300MC TrenchFET® PROCESS TECHNOLOGY |               |  |  |  |  |  |
|-------------------------------------|---------------|--|--|--|--|--|
| Sample size                         | 26 404        |  |  |  |  |  |
| Equivalent device hours             | 3 449 960 047 |  |  |  |  |  |
| Failure rate in FIT                 | 0.264         |  |  |  |  |  |

Failure rate in FIT is calculated according to JEDEC® standard JESD85, Methods for calculating failure rates in units of FITs, based on accelerated high temperature operating life test results by using an apparent activation energy of 0.7 eV. The junction temperature of the device at use is assumed to be 55 °C. A constant failure rate distribution is assumed. The upper confidence bound of the failure rate is 60 %.

| ENVIRONMENTAL AND PACKAGE TESTING DATA FOR POWERPAK® SO-8L |             |                |                          |             |                 |  |  |  |  |  |
|--|-------------|----------------|--------------------------|-------------|-----------------|--|--|--|--|--|
| STRESS   | SAMPLE SIZE | DEVICE HR./CYC | CONDITION                | TOTAL FAILS | FAIL PERCENTAGE |  |  |  |  |  |
| Bond int.  | 520         | 270 000        | 200 °C, N2               | 0           | 0.00            |  |  |  |  |  |
| HAST   | 1394        | 155 800        | 130 °C, 85 % RH          | 0           | 0.00            |  |  |  |  |  |
| Pressure pot   | 1886        | 236 160        | 121 °C, 15 PSIG          | 0           | 0.00            |  |  |  |  |  |
| Temp. cycle  | 1968        | 2 501 000      | -55 °C to +150 °C        | 0           | 0.00            |  |  |  |  |  |
| Solderability  | 255         | 2 040          | 8 hours                  | 0           | 0.00            |  |  |  |  |  |
| Power cycle  | 1066        | 18 368 000     | ΔT <sub>J</sub> = 100 °C | 0           | 0.00            |  |  |  |  |  |
| Solder dunk  | 1099        | 3 297          | 260 °C, 10 s             | 0           | 0.00            |  |  |  |  |  |



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Vishay

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